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Enhancement in the efficiency of an organic–inorganic hybrid solar cell with a doped P3HT hole-transporting layer on a void-free perovskite active layer

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Significant enhancement in the power conversion efficiency of an organic–inorganic hybrid solar cell was achieved by the use of suitably doped poly(3-hexylthiophene-2,5-diyl) (P3HT) spin coated on a 99.5% void-free perovskite layer prepared on a TiO_x electron-transporting layer. The 9.2% device efficiency with pristine P3HT was increased to 12.4%.

Solution-processable organic–inorganic hybrid solar cells utilizing a methylammonium halide lead perovskite ($(\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Cl}_x)$) semiconductor have quickly achieved a power conversion efficiency (PCE) as high as 15%.^{1–4} The high efficiency is due largely to high mobility of the perovskite ($>10 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$),⁵ and the long diffusion length for both holes and electrons in the perovskite layer.^{6,7} The uniformity of the perovskite layer and the efficiency of extracting free charge carriers through the electron- and hole-transporting layers (HTLs and ETLs) are two crucial factors to be optimized for further increase in the PCE.^{8–13} Poly(3-hexylthiophene-2,5-diyl) (P3HT, Fig. 1a), an inexpensive and readily available HTL material,^{14–16} has shown a PCE value of 10.8%,¹⁶ which is, however, not as satisfactory as those given by the use of structurally more elaborate HTL materials such as 2,2,7,7-tetrakis-(*N,N*-di-*p*-methoxyphenylamine) 9,9-bifluorene (spiro-OMeTAD).^{12–14} We report here that an HTL composed of a ternary mixture of P3HT, an ionic dopant and a third additive, spin coated on a uniform and void-free (99.5% coverage) perovskite layer on indium tin oxide (ITO)/ TiO_x (Fig. 1b and d) brings about a considerable increase in the PCE value to 12.4% under the standard AM 1.5 conditions (Fig. 1c). This device shows an external quantum efficiency (EQE) of nearly 90% for a wide range of visible light (inset in Fig. 1d). The ionic dopant bis (trifluoromethane)sulfonimide lithium salt (Li-TFSI) was found to increase the carrier density in HTL, while the third component, 2,6-di-*tert*-butylpyridine (D-TBP) (Fig. 1a) which was examined for the first in this field research, was found to increase the mobility of the HTL as determined by mobility measurements, and as supported by the absorption spectra and X-ray diffraction (XRD) analysis that indicated enhanced ordering of the P3HT polymer chains. Such a phenomena have not been reported in

the previous study in the HTL doped with a popular additive, 4-*tert*-butylpyridine (TBP).¹⁵

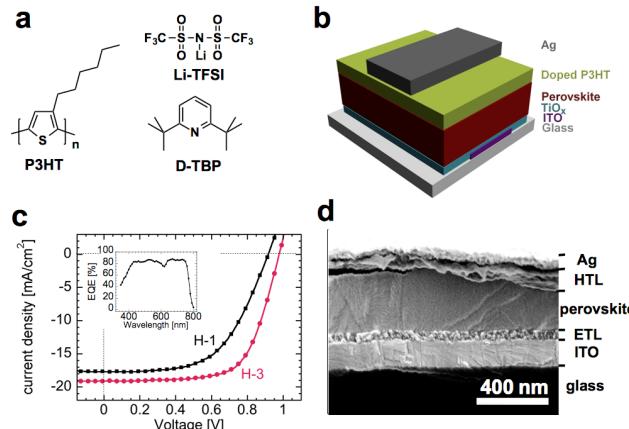


Figure 1. An organic–inorganic hybrid solar cell featuring a P3HT-based HTL on a void-free perovskite semiconductor layer. (a) The molecular structures of P3HT, ionic dopant Li-TFSI and additive D-TBP. (b) Illustration of the present solar cell architecture. (c) J – V curves of the cell using different P3HTs (H-1 (pristine P3HT) or H-3 (P3HT containing Li-TFSI and D-TBP)) under 1 sun irradiation (AM 1.5G, 100 mW/ cm^2). Inset shows the EQE spectrum of the cell using H-3. (d) Cross-section SEM image of the perovskite solar cell using H-3.

The uniformity and crystallinity of the perovskite are crucial to achieving high efficiency in hybrid solar cells,¹⁶ and scanning electron microscopy (SEM) using a low landing voltage (1 kV) was found to provide a powerful tool for the analysis of the surface and the cross-section of organic and inorganic layers at *ca.* 1-nm resolution.¹⁷ A TiO_x precursor solution was spin coated on a UV/ozone-treated ITO at 3000 rpm for 30 s and sintered at 500 °C for 30 min to form a flat ETL with a thickness of *ca.* 45 nm (Fig. 1d). This ETL is a uniform film made of nanoparticles of 15- to 20-nm diameter (and see ESI, Fig. S1†). We then spin coated, a 20 wt% solution of a mixture of $\text{CH}_3\text{NH}_3\text{I}:\text{PbCl}_2$ in a 3:1 mole ratio in DMF at a slow spinning rate of 500 rpm for 60 s, and it was heated at 95 °C for 100 min, followed by rapid cooling to the room temperature

COMMUNICATION

Journal Name

under nitrogen atmosphere. The crystalline perovskite active layer thus prepared was *ca.* 300 nm thick.

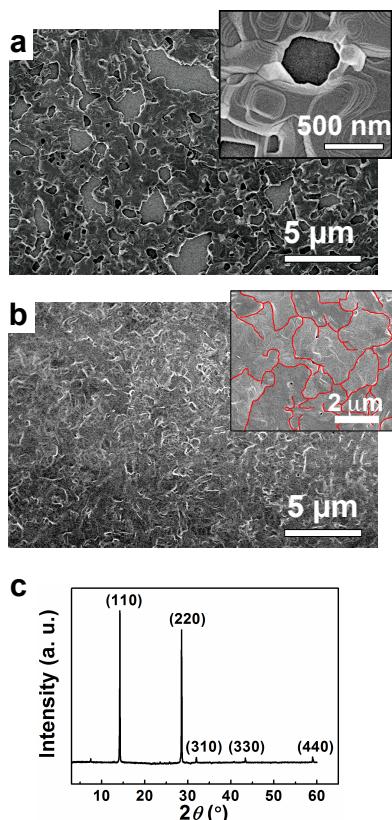


Figure 2. SEM and XRD data of the perovskite layer coated on ITO/TiO_x. Perovskite layer was slowly cooled (a) or rapidly cooled (b) after the heating at 95 °C. Inset shows large magnifications images of same sample. Red lines in the inset indicate the boundaries of the crystal grains. (d) The XRD pattern of the perovskite layer coated on ITO/TiO_x.

We noticed that the slow cooling tends to extend the void area, thus we adapted rapid cooling after the heating to prevent the void formation. The SEM and XRD analysis indicated that rapidly cooled perovskite layer shows much better defined morphological and crystallographic properties than those reported previously.¹⁸

The cross-section view of the solar cell device formed on the rapidly cooled perovskite in Fig. 1d shows that the perovskite layer is very dense and uniform. The top view in the Fig. 2b is representative of nine different areas of the rapidly cooled perovskite taken from three different samples, and indicates that 99.55 ± 0.24% of the surface is free of voids—a value significantly (see ESI, Fig. S2[†]) higher than the reported coverage of 95%.¹⁶ To the contrary, the perovskite layer formed by slow cooling (Fig. 2a) exhibited much larger void (*i.e.*, a 82.2% void free region, see ESI, Fig. S3[†]), which might be caused by the formation of larger crystallite as observed the clearly visible step and terrace structures (Fig. 2a inset). Although this subject is still under investigation, we could ascribe that the crystal growth during the cooling process might be the key for morphological control of the perovskite layer. The devices fabricated on the void-rich perovskite (*i.e.*, 82.2% void-free) showed, not unexpectedly, only 6–8% PCE as opposed to the one made on a 99.5% void-free perovskite that showed 12.4% PCE.

XRD of the void-free perovskite film in Fig. 2c shows sharp and strong diffraction peaks at 14.19° and 28.48° due to the (110) and (220) crystal planes, and additional 31.88°, 43.33° and 58.7° peaks

due to (310), (330) and (440) planes, respectively.^{9,16} Scherrer's analysis of the peaks¹⁹ gave a crystal grain size of *ca.* 1.5 μm, which agrees with the grain size of *ca.* 2 μm estimated from the top SEM view (Fig. 2b inset with red lines indicating grain boundaries). This crystal grain size is much larger than the reported sizes of *ca.* 0.5 μm.²⁰

We next fabricated solar cell devices on the 99.5%-void-free perovskite layer, and examined the effects of doping of the P3HT-based HTL. The HTLs containing P3HT, Li-TFSI, and D-TBP as dopants in a variety of ratios are denoted as H-1 to H-4 as shown in Table 1 (see ESI, Fig. S4[†] and Table S1[†] for two additional HTLs H-5 and H-6 using Li-TFSI and D-TBP in different ratios). We chose the D-TBP additive rather serendipitously, knowing that it is a hindered base well-known in organic chemistry that can only react with proton without interaction with a Lewis acidic metal atoms (*e.g.*, Pb cation).

After spin coating at 2500 rpm for 30 s an HTL on the void-free perovskite followed by vacuum deposition of the Ag electrode, we examined the performance of the solar cells under simulated AM 1.5, 100 mW cm⁻² irradiation (Fig. 1c). We summarize four representative results using H-1 to H-4 (Table 1). H-1 refers to pristine P3HT, H-2 to P3HT doped with Li-TFSI, H-3 to P3HT doped with Li-TFSI and D-TBP, and H-4 to P3HT doped only with D-TBP. The device coated with pristine P3HT (H-1) showed a PCE value of 9.2%, which is among the highest values reported for P3HT-based perovskite solar cells.¹⁶ The devices using H-2 showed a value of 11.2% and the device with H-3 showed a PCE of 12.4%, a 35% improvement over the 9.2% value for H-1. Short-circuit current density (*J*_{SC}), open-circuit voltage (*V*_{OC}) and fill-factor (FF) values are 19.1 mA cm⁻², 0.98 V and 66.3%, respectively. A small dip around 600 nm in the EQE spectrum (Fig. 1c inset) is probably because of the absorption edge of the P3HT layer.²¹ The fabrication of the H-3 devices examined for 23 independent batches (see ESI, Fig. S6[†]) was found to be reproducible with the average PCE of 11.1% ($\pm 0.55\%$). In addition, the photocurrent density and the power conversion efficiency remained constant when applying 0.7 V voltage under the irradiation suggesting that our solar cell is stable under the operation conditions (see ESI, Fig. S6[†]).²²

Upon addition of the Li-TFSI dopant to P3HT, *J*_{SC} increased to a value of 19.3 mA cm⁻², close to the saturation value.¹⁶ While Li-TFSI contributed to the slight increase in *V*_{OC} and FF as well as in *J*_{SC}, D-TBP contributed to a further increase in the former two without significant loss in *J*_{SC}. The marked increase in FF is a direct consequence of the greatly decreased series resistance (*R*_S) from 12.4 Ω cm² for the H-1 cell to 8.9 Ω cm² for the H-2 cell and 8.5 Ω cm² for the H-3 cell, which is reflected in the 100-times larger conductivities in the two-terminal devices of the H-2 and H-3 thin films ($\sigma = 5.4 \times 10^{-2}$ and 6.4×10^{-2} S m⁻¹, respectively) than that of the H-1 thin films (5.4×10^{-4} S m⁻¹) (Table 1 and Fig. 3a).

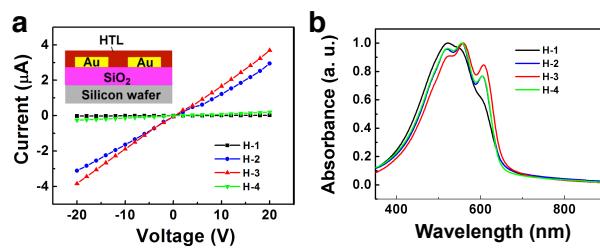


Figure 3. Electronic and optical properties of different HTLs. (a) The *I*-*V* curves of different HTLs bridged on the gap electrode. Inset shows the device structure of two-terminal devices having a channel width of 325 μm and a length of 9 μm. (b) The absorption spectra of different HTLs coated on the quartz substrate.

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Table 1. Details of the photovoltaic performance of the solar cells using different HTLs, and the conductivity and HOMO level of different HTL films.

HTL	P3HT ^a (mg)	Li-TFSI ^b (mg)	D-TBP ^c (mg)	J_{sc} (mA·cm ⁻²)	V_{oc} (V)	FF (%)	PCE (%)	R_s (Ω·cm ²)	σ (S·m ⁻¹)	HOMO ^d (eV)
H-1	15	0	0	17.7	0.92	56.2	9.2	12.4	5.4×10^{-4}	-4.70
H-2	15	0.54	0	19.3	0.94	61.5	11.2	8.9	5.4×10^{-2}	-4.79
H-3	15	0.54	8.8	19.1	0.98	66.3	12.4	8.5	6.4×10^{-2}	-4.80
H-4	15	0	8.8	17.5	0.89	41.6	6.5	48.3	3.4×10^{-3}	-4.70

^aP3HT dissolved in 1 ml of chlorobenzene, ^bLi-TFSI dissolved in 6.8 µl of acetonitrile, ^c10.2 µl D-TBP was added to the P3HT:Li-TFSI mixture solution,^dThe HOMO level was estimated from photoelectron yield spectroscopy analysis.

While Li-TFSI increased the performance by increasing the carrier density, D-TBP may do so by increasing the mobility originating from the enhanced ordering of the P3HT polymer chains; that is, Fig. 3b shows the absorption spectra of H-1 to H-3 as well as H-4 (P3HT doped with D-TBP), where we see the appearance of increased peaks by addition of D-TBP (H-3 and H-4) at 561 nm and 610 nm with concomitant decrease in the peak at 529 nm. This change in absorption is known to be the signature of enhanced ordering of P3HT in the solid state.²³ Li-TFSI also enhances the ordering (H-2) and may cooperate with D-TBP. This conclusion was corroborated by XRD analysis and the field-effect mobility measurement. Thus, we saw first a marked enhancement of the 2θ peak at 5.25° that corresponds to a 1.68-nm *d*-spacing of the lamella layers, as well as at 23.5° corresponding to a 0.38-nm π – π interactive stacking distance,²³ and also a four-times higher mobility of H-4 than H-1 (see ESI, Fig. S8[†]).

Photoelectron yield spectroscopy analysis of the HTLs (H-1 to H-4) indicated that the HOMO level decreases upon addition of Li-TFSI (from -4.70 eV for H-1 to -4.79 eV for H-2), but not upon addition of D-TBP (-4.70 eV for H-4) (see ESI, Fig. S9[†]). Thus Li-TFSI lowers the HOMO of HTL closer to the valence band of the perovskite (-5.37 eV, see ESI Fig. S10[†]), which would help to increase the device performance.²⁴

Conclusions

In summary, we have prepared an extremely homogeneous perovskite layer that is 99.5% free of voids, and fabricated an HTL based on the popular material P3HT. An ionic dopant Li-TFSI contributed to the increase in PCE by increasing the conductivity of the HTL, and a neutral additive D-TBP did so by enhancement of the ordering of the polymer chains of P3HT in the HTL. Thus, a ternary HTL, H-3, afforded 12.4% PCE—the highest PCE reported for P3HT-based HTL in perovskite solar cells with it high reproducibility.

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Notes and references

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[†] Electronic Supplementary Information (ESI) available: [Experimental details]. See DOI: 10.1039/c000000x/

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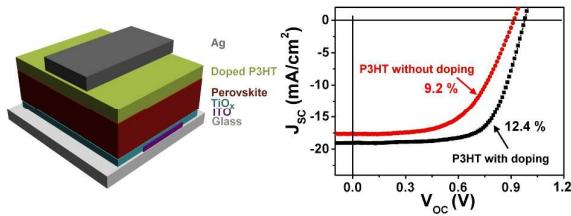
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A table of contents entry



A 99.5% void-free perovskite layer with doped-P3HT hole-transporting layer showed highest PCE among the P3HT based hybrid solar cells.